XP161A1265PR

ETR1123_001

Power MOSFET

■ GENERAL DESCRIPTION

The XP161A1265PR is an N-channel Power MOSFET with low on-state resistance and ultra high-speed switching characteristics.

Because high-speed switching is possible, the IC can be efficiently set thereby saving energy.

A gate protect diode is built-in to prevent static damage.

The small SOT-89 package makes high density mounting possible.

■APPLICATIONS

- Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems

■FEATURES

Low On-State Resistance : Rds(on)=0.055 Ω @ Vgs=4.5V

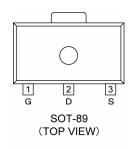
: Rds(on)=0.095 Ω @ Vgs=2.5V

Ultra High-Speed Switching Gate Protect Diode Built-in **Driving Voltage** : 2.5V **N-Channel Power MOSFET**

DMOS Structure

Small Package : SOT-89

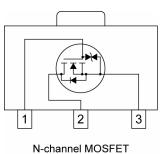
■PIN CONFIGURATION



■ PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTION
1	G	Gate
2	D	Drain
3	S	Source

■EQUIVALENT CIRCUIT



(1 device built-in)

■ ABSOLUTE MAXIMUM RATINGS

Ta = 25°C

PARAMETER	SYMBOL	RATINGS	UNITS
Drain-Source Voltage	Vdss	20	V
Gate-Source Voltage	Vgss	±12	V
Drain Current (DC)	ld	4	Α
Drain Current (Pulse)	ldp	16	Α
Reverse Drain Current	ldr	4	Α
Channel Power Dissipation *	Pd	2	W
Channel Temperature	Tch	150	°C
Storage Temperature Range	Tstg	-55~150	°C

^{*} When implemented on a ceramic PCB

■ELECTRICAL CHARACTERISTICS

DC Characteristics Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain Cut-Off Current	ldss	Vds=20V, Vgs= 0V	-	-	10	μΑ
Gate-Source Leak Current	lgss	Vgs= ±12V, Vds=0V	-	-	±10	μΑ
Gate-Source Cut-Off Voltage	Vgs(off)	Id= 1mA, Vds= 10V	0.7	-	1.4	V
Drain-Source On-State Resistance*1	Rds(on)	Id= 2A, Vgs= 4.5V	-	0.042	0.055	Ω
		Id= 2A, Vgs= 2.5V	-	0.070	0.095	Ω
Forward Transfer Admittance*1	Yfs	ld= 2A, Vds= 10V	-	8	-	S
Body Drain Diode Forward Voltage	Vf	If= 4A, Vgs= 0V	-	0.85	1.1	V

^{*1} Effective during pulse test.

Dynamic Characteristics

Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Capacitance	Ciss	Vds= 10V, Vgs=0V f= 1MHz	-	320	-	pF
Output Capacitance	Coss		-	190	-	pF
Feedback Capacitance	Crss		-	80	-	pF

Switching Characteristics

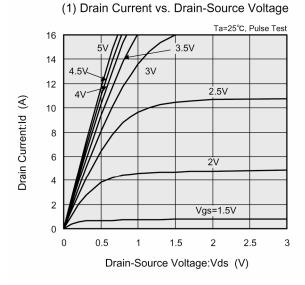
Ta = 25°C

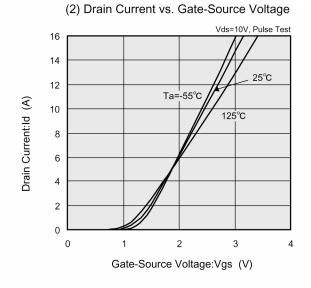
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-On Delay Time	td (on)	Vgs= 5V, Id=2A Vdd= 10V	-	10	-	ns
Rise Time	tr		-	15	-	ns
Turn-Off Delay Time	td (off)		-	55	-	ns
Fall Time	tf		ı	40	ı	ns

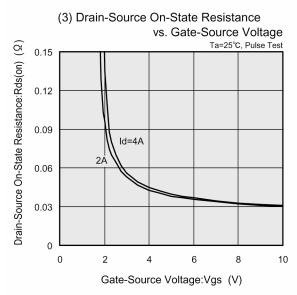
Thermal Characteristics

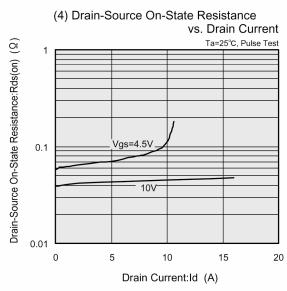
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal Resistance (Channel-Ambience)	Rth (ch-a)	Implement on a ceramic PCB	-	62.5	-	°C/W

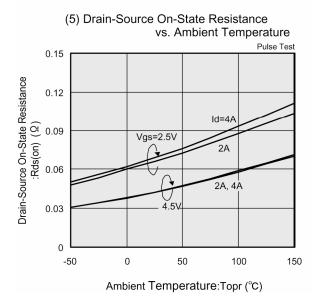
■TYPICAL PERFORMANCE CHARACTERISTICS

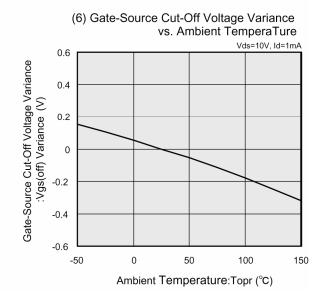




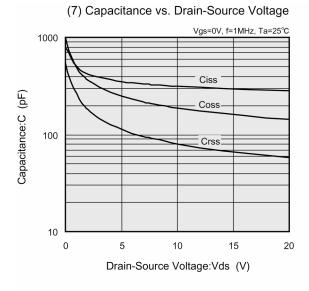


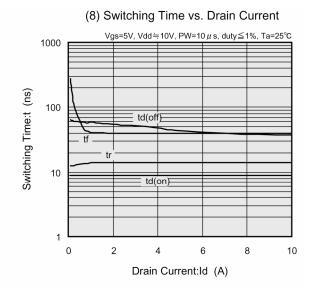


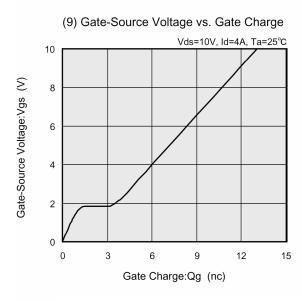


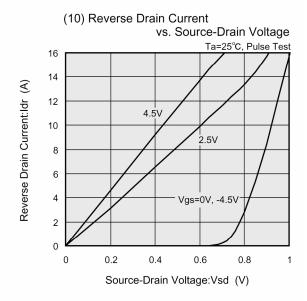


■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

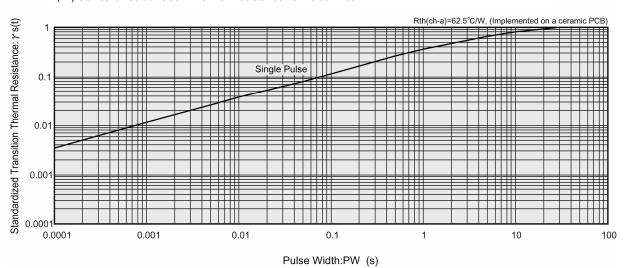












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